



Intel[®] Server System SC5400RA Tested Memory Report

Revision 21.0
November 2008

Revision History

| Date | Rev | Modifications |
|---------|------|--|
| Nov/06 | 1.0 | Initial release. |
| Jan/07 | 2.0 | Added Hynix 512MB parts. Added Micron 1GB parts. Added Qimonda 2GB part. (In shaded area) |
| Feb/07 | 3.0 | Added Hynix and Qimonda 512MB parts. (In shaded area) |
| Feb/07 | 4.0 | Added Qimonda 512MB parts. (In shaded area) |
| Feb/07 | 5.0 | Added Qimonda and Samsung 512MB parts. Added Micron, Qimonda, and Samsung 1GB parts. Added Kingston, Micron, and Qimonda 2GB parts. Updated vendor contact information. (In shaded area) |
| Mar/07 | 6.0 | Updated contact information. Added Kingston 512MB and 2GB parts. (In shaded area) |
| Apr/07 | 7.0 | Added Micron 512MB parts. Added Micron and Kingston 1GB parts. Added Kingston, Qimonda, Samsung, and ATP Electronics 2GB parts. Added Micron 4GB parts. (In shaded area) |
| May/07 | 8.0 | Added Smart, Micron, and ATP Electronics 1GB parts. Added Micron and Kingston 2GB parts. (In shaded area) |
| May/07 | 9.0 | Additional memory parts added. (In shaded area) |
| June/07 | 10.0 | Additional memory parts added. (In shaded area) |
| July/07 | 11.0 | Additional memory parts added. (In shaded area) |
| Aug/07 | 12.0 | Additional memory parts added. (In shaded area) |
| Oct/07 | 13.0 | Updated some contact information. Additional memory parts added. (In shaded area) |
| Oct/07 | 14.0 | Removed incorrect part number. |
| Nov/07 | 15.0 | Added an AMB revision notes. Added additional memory parts (in shaded area). |
| Jan/08 | 16.0 | Removed modules built with Qimonda C1 stepping AMBs. Added additional memory parts (in shaded area). |
| Mar/08 | 17.0 | Added additional memory parts (in shaded area). |
| June/08 | 18.0 | Added additional memory parts (in shaded area). |
| June/08 | 19.0 | Added additional memory parts (in shaded area). |
| Nov 08 | 20.0 | Added additional memory parts (in shaded area). |
| Nov 08 | 21.0 | Added additional memory parts (in shaded area). |

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The hardware vendor remains solely responsible for the design, sale and functionality of its product, including any liability arising from product infringement or product warranty. Only approved software drivers and accessories that are recommended for the revision number of the boards and system being operated should be used with Intel products. Please note that, as a result of warranty repairs or replacements, alternate software and firmware versions may be required for proper operation of the equipment.

The Intel® Server System SC5400RA may contain design defects or errors known as errata which may cause the product to deviate from published specifications. Current characterized errata are available on request.

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Please Note: DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or vice-versa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each Rank on the memory module. Mixing of dissimilar memory is NOT recommended.

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Overview of Memory Testing

The following test processes are used to qualify Dual In-Line Memory Modules (DIMMs) for use with the Intel® Server System SC5400RA. Memory is a vital subsystem in a server. Intel requires that strict guidelines be met before a DIMM vendor is added to the Tested Memory Report. To be included on the list as a fully supported DIMM, the memory must undergo rigorous tests to ensure that the product will perform the intended server product functions. Memory qualification for Intel server, workstation and RAID controller products is performed both by Intel's Memory Validation Lab (MVL) and by an independent external test lab, Computer Memory Test Lab* (CMTL).

The Tested Memory Lists for Intel's server boards, workstation boards, and RAID controller products categorize memory modules as Advanced Tested. The Advanced Testing process includes a standard paper qualification and then is followed by two levels of functional testing. DIMMs that have completed and passed Advanced Testing are considered to be compatible with the product on which they were tested, and with the test software and operating systems that was used during the test process.

Note: Memory qualification for main memory is done by testing identical memory modules in all DIMM slots. Memory qualification does not include testing of mixed DIMM type and/or vendors. Mixing of DIMM type and/or vendors is not recommended.

1.1 Paper Qualification

A paper qualification is performed to verify that the specifications of a given DIMM meet Intel's memory specifications for a given product. Specification criteria reviewed include: critical timings, electrical characteristics, timing requirements, environmental requirements, and packaging requirements.

1.2 Functional Testing

After a given DIMM passes the standard paper qualification, functionality of the DIMM is then tested with the intended Intel product. Two levels of functional testing is performed; Standard and Advanced.

Standard functional testing requires that the given DIMM and Intel product combination operate with no failures for a period of no less than 24 hours for both minimum and maximum DIMM configurations. Testing is performed using a Microsoft Windows* operating system and a custom test package. The test systems operate with standard voltage and at room temperature.

1.3 Advanced functional testing

Advanced functional testing requires that the given DIMM and Intel product combination operate with no failures for a period of no less than 24 hours for both minimum and maximum DIMM configurations. Testing is performed with multiple operating systems and various custom test packages. Each test configuration is tested with various voltage and temperature margin conditions.

1.4 Computer Memory Test Lab*

Computer Memory Test Lab, also known as "CMTL*" is a leading memory test organization responsible for testing a broad range of memory products. A memory product, which receives a "PASS" after being tested by CMTL, means it functions correctly and consumers can use the product to perform the intended server functions. In order to pass these stringent standards, memory products must maintain the highest manufacturing procedures and pass an exacting battery of tests. Testing is performed with Intel supplied equipment and procedures defined by Intel's various functional testing levels.

CMTL* Contact Information:

Office: (949) 716-8690

Main Fax: (949) 716-8691

Computer Memory Test Lab (CMTL)

24 Hammond Suite F

Irvine, CA 92618

<http://www.cmtlabs.com/>

Intel® Server System SC5400RA Memory Sub-system

The Intel® Server System SC5400RA main memory subsystem was designed to support Fully Buffered Dual In-line (FBD) Registered DDR2-533 and DDR2-667 FBDIMM memory ECC Synchronous Dynamic Random Access Memory (SDRAM). Other industry naming conventions for DDR2-533 includes PC2-4200, and DDR2-667 includes PC2-5300.

Note: Only DDR2 DIMMs that are Fully Buffered is supported on these server boards.

This server board provides 16 DIMMs slots. It is capable of supporting a minimum of 512MBs using a single 512MB FBDIMM, and a maximum of up to 64GB. Supported FBDIMM capacities for main memory include: 512MB, 1GB, 2GB, and 4GB.

Supported FBDIMM capacities for main memory include: 256MB, 512MB, 1GB, 2GB, and 4GB.

1.1 Main Memory Population

The Intel® Server System SC5400RA supports two memory riser cards. Each memory riser card has 8 eight DIMM, grouped into four DIMM channels for main memory. DIMMs within each bank should be identical (same manufacturer, CAS latency, number of rows, columns and devices, timing parameters etc.). Although DIMMs within a bank must be identical, the BIOS supports various DIMM sizes and configurations allowing memory between banks to be different. Memory sizing and configuration is guaranteed only for qualified DIMMs approved by Intel.

DIMM population rules depend on the operating mode of the memory controller, which is determined by the number of DIMMs installed. DIMMs must be populated in pairs. DIMM pairs are populated in the following DIMM slot order: A1 & B1, C1 & D1, A2 & B2, C2 & D2, and so on. DIMMs within a given pair must be identical with respect to size, speed, and organization. However, DIMM capacities can be different between different DIMM pairs.

For example, a valid mixed DIMM configuration may have 512MB DIMMs installed in DIMM Slots A1 & B1, and 1GB DIMMs installed in DIMM slots C1 & D1.

1.1.1 Memory Sub-system

The MCH masters four fully-buffered DIMM (FBD) memory channels. FBD memory utilizes a narrow high-speed, frame-oriented interface referred to as a channel. The four FBD channels are organized into two branches, with two channels on each branch. Each branch is supported by a separate memory controller. The two channels on each branch operate in lock-step to increase FBD bandwidth.

The four channels are routed to sixteen DIMM sockets and are capable of supporting registered DDR2-533 and DDR2-667 FBDIMM memory (stacked or unstacked). The read bandwidth of each FBDIMM channel is 4.25 GB/s for DDR2-533 FBDIMM memory, which gives a total read bandwidth of 17 GB/s for four DIMM channels. The read bandwidth of each FBDIMM channel is 5.35 GB/s for DDR2-667 FBDIMM memory, which gives a total read bandwidth of 21.4 GB/s for four DIMM channels.

The Intel® Server System SC5400RA supports two DIMM riser cards. Each DIMM riser card supports eight DIMM sockets, for total of sixteen DIMM sockets.

FBD memory channels are organized into two branches for support of RAID 1 (mirroring). A pair of channels becomes a branch in which Branch 0 consists of channels A and B, and Branch 1 consists of channels C and D. Branch 0 is routed to DIMM riser card 1 and Branch 1 is routed to DIMM riser card 2 (closest to the edge of the server board).

To boot the system, the system BIOS on the server board uses a dedicated I²C bus to retrieve DIMM information needed to program the MCH memory registers. The following figure and table provides the I²C addresses for each DIMM socket and it identifies the channels on each DIMM riser card.

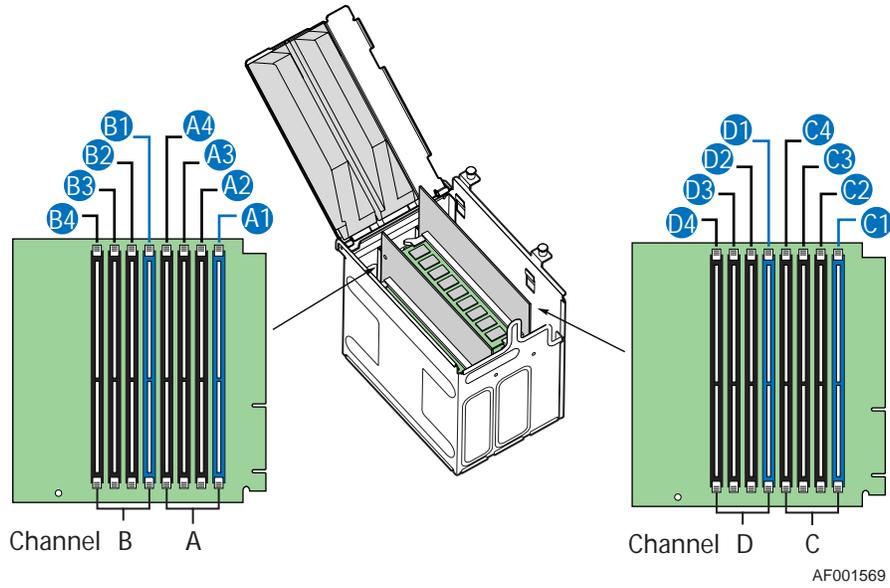


Table 1. I²C Addresses for Memory Module SMB

| Riser Card 1 | | Riser Card 2 | |
|--------------|---------|--------------|---------|
| Device | Address | Device | Address |
| DIMM A1 | 0xA0 | DIMM C1 | 0xA0 |
| DIMM A2 | 0xA2 | DIMM C2 | 0xA2 |
| DIMM A3 | 0xA4 | DIMM C3 | 0xA4 |
| DIMM A4 | 0xA6 | DIMM C4 | 0xA6 |
| DIMM B1 | 0xA0 | DIMM D1 | 0xA0 |
| DIMM B2 | 0xA2 | DIMM D2 | 0xA2 |
| DIMM B3 | 0xA4 | DIMM D3 | 0xA4 |
| DIMM B4 | 0xA6 | DIMM D4 | 0xA6 |

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The following table lists the current supported memory types:

| FBDIMM-533 CL4 & FBDIMM-667 CL5 Memory Matrix | | | | | | |
|--|--------------------------|----------------------|---------------------------|-----------------------------------|---|---------------|
| DIMM Capacity | DIMM Organization | SDRAM Density | SDRAM Organization | # SDRAM Devices/rows/Ranks | # Address bits rows/Ranks/column | Ranked |
| 256MB | 32M x72 | 256Mbit | 64M x 4 | | 13/11/2 | |
| 256MB | 32M x72 | 256Mbit | 32M x 8 | | 13/10/2 | |
| 512MB | 64M x72 | 256Mbit | 128M x 4 | | 13/12/2 | |
| 512MB | 64M x72 | 256Mbit | 64M x 8 | | 13/11/2 | |
| 512MB | 64M x72 | 512Mbit | 128M x 4 | | 14/11/2h | |
| 512MB | 64M x72 | 512Mbit | 64M x 8 | | 14/10/2 | |
| 1GB | 128M x 72 | 512Mbit | 256M x 4 | | 14/12/2 | |
| 1GB | 128M x 72 | 512Mbit | 128M x 8 | | 14/11/2 | |
| 1GB | 128M x 72 | | 256M x 4 | | 14/11/3 | |
| 1GB | 128M x 72 | | 128M x 8 | | 14/10/3 | |
| 2GB | 256M x72 | | 512M x 4 | | 15/11/3 | |
| 2GB | 256M x72 | | 256M x 8 | | | |
| 4GB | | | | | | |

Intel® Server System SC5400RA Main Memory Tested

The following tables list DIMM devices tested to be compatible with the Intel® Server System SC5400RA. The list of tested memory is periodically updated as qualified memory is added during the production life of the Intel product.

Intel strongly recommends the use of ECC memory in all server products.

Memory modules not listed in the following tables have not been tested for compatibility and their use with the Intel® Server System SC5400RA may result in unpredictable operation and data loss.

Caution: Third party memory vendors may use the same module part number with different DRAM vendors and die revisions. To insure proper system operation, verify that each DRAM vendor and die revision has been separately tested and qualified. Please notify CMTL if there is a discrepancy. This list is subject to change without notice.

Note: This list is not intended to be all-inclusive. It is provided as a convenience to Intel's general customer base, but Intel does not make any representations or warranties whatsoever regarding the quality, reliability, functionality, or compatibility of these memory modules.

Intel® Server System SC5400RA
Fully Buffered ECC, DDR2-533 DIMM Modules
512 MB Sizes (64Mx72)

| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
|--------------|------------------------|------------------|-------------|-----------------|------------|--------------|------------------|-------------------|------|---------|
| Hynix | HYMP564F72 BP8D2-C4 | HY5PS12821BFP-C4 | Hynix | | IDT | 1.5 | FDHS | (64Mx8)*9 | 1 | 1/24/07 |

Fully Buffered ECC, DDR2-667 DIMM Modules
512 MB Sizes (64Mx72)

| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
|--------------------|--------------------------|-------------------------|-------------|---------------------------|------------|--------------------|------------------|-------------------|------|----------|
| Samsung | M395T6553CZ 4-CE61 | K4T51083QC | Samsung | | IDT | 1.5 | FDHS | (64Mx8)*18 | 2 | 11/10/06 |
| Qimonda | M395T6553CZ 4-CE60 | K4T51083QC | Qimonda | | Intel | GB C0 ¹ | FDHS | (64Mx8)*9 | 1 | 11/10/06 |
| Hynix | HYMP564F72 BP8D2-Y5 | HY5PS12821BFP-Y5 | Hynix | | IDT | 1.5 | FDHS | (64Mx8)*9 | 1 | 1/16/07 |
| Hynix | HYMP564F72 BP8N2-Y5 | HY5PS12821BFP-Y5 | Hynix | | Intel | GB C0 ¹ | FDHS | (64Mx8)*9 | 1 | 1/16/07 |
| Hynix | HYMP564F72 BP8D2-Y5 | HY5PS12821BFP-Y5 | Hynix | | IDT | 1.5 | FDHS | (64Mx8)*9 | 1 | 1/16/07 |
| Hynix | HYMP564F72 BP8N2-Y5 | HY5PS12821BFP-Y5 | Hynix | | Intel | GB C0 ¹ | FDHS | (64Mx8)*9 | 1 | 1/16/07 |
| Qimonda | HYS72T64400 HFD-3S-B | HYB18T512800AF-3S-B | Qimonda | | IDT | C1 | FDHS | (64Mx8)*9 | 1 | 2/9/07 |
| Qimonda | HYS72T64400 HFN-3S-B | HYB18T512800AF-3S-B | Qimonda | | Intel | D1 | FDHS | (64Mx8)*9 | 1 | 2/9/07 |
| Qimonda | HYS72T64400 HFN-3S-A | HYB18T512800AF | Qimonda | | Intel | GB C0 ¹ | FDHS | (64Mx8)*9 | 1 | 2/26/07 |
| Samsung | M395T6553EZ 4-CE65 | K4T51083QE | Samsung | | Intel | GB D1 | FDHS | (64Mx8)*9 | 1 | 2/26/07 |
| Kingston | KVR667D2S8 F5/512I | E5108AGBG-6E-E rev G | Elpida | 2025285- 002.A00 na | Intel | D1 | Foxconn | (64Mx8)*9 | 1 | 3/19/07 |
| Micron | MT9HTF6472 FY-667B4E3 | MT47H64M8CB-3 | Micron | | Intel | GB C0 ¹ | FDHS | (64Mx8)*9 | 1 | 3/28/07 |
| Micron | MT9HTF6472 FY-667D5E4 | MT47H64M8-3 | Micron | | Intel | GB D1 | FDHS | (64Mx8)*9 | 1 | 3/28/07 |
| Kingston | KVR667D2S8 F5/512I | NT5TU64M8BE-3C rev B | Nanya | 2025285- 002.A00 na | | D1 | Foxconn | (64Mx8)*9 | 1 | 5/22/07 |
| Crucial Technology | CT6472AF667 .9FD5D4 | MT47H64M8B6- 3:D | Micron | | IDT | C1 | FDHS | (64Mx8)*9 | 1 | 6/18/07 |
| Crucial Technology | CT6472AF667 .9FD5E4 | MT47H64M8B6- 3:D | Micron | | Intel | GB D1 | FDHS | (64Mx8)*9 | 1 | 6/18/07 |
| Micron | MT9HTF6472 FY-667D5D4 | MT47H64M8B6- 3:D | Micron | | IDT | C1 | FDHS | (64Mx8)*9 | 1 | 6/18/007 |

¹ The GB C0 AMB revision does not support closed-loop throttling.

| Fully Buffered ECC, DDR2-667 DIMM Modules 512 MB Sizes (64Mx72) | | | | | | | | | | |
|--|-------------------------|-------------------------|--------------------|------------------------|-------------------|---------------------|-------------------------|--------------------------|-------------|-------------|
| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
| Qimonda | HYS72T64400 HFE-3S-B | HYB18T512800AF | Qimonda | | NEC | B5+ | FDHS | (64Mx8)*9 | 1 | 6/18/07 |
| Samsung | M395T6553EZ 4-CE66 | K4T51083QE- ZCE6 | Samsung | | IDT | C1 | FDHS | (64Mx8)*9 | 1 | 6/18/07 |
| Hynix | HYMP564F72 BP8D3-Y5 | HY5PS12821BFP- Y5 | Hynix | | IDT | C1 | FDHS | (64Mx8)*9 | 1 | 1/7/08 |
| Hynix | HYMP564F72 BP8N3-Y5 | HY5PS12821BFP- Y5 | Hynix | | Intel | GB D1 | FDHS | (64Mx8)*9 | 1 | 1/7/08 |

(+) This vendor is part of the CMTL Certification program. This means this part has/will be tested across all compatible Intel Server Boards. For further information contact CMTL @ <http://cmtlabs.com/>

Note: The use of x4 FBDIMMs will only be supported with the server system operating in "Performance" mode (default). The use of x4 FBDIMMs while the server system is configured to operate in "Acoustics" mode is not supported.

Intel® Server System SC5400RA
Fully Buffered ECC, DDR2-667 DIMM Modules
1 GB Sizes (128Mx72)

| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
|----------------------------|-------------------------|------------------------|-------------|-------------------------|------------|--------------------|------------------|-------------------|------|----------|
| Samsung | M395T2953CZ4-CE60 | K4T51083QC | Samsung | | Intel | GB C0 ¹ | FDHS | (64Mx8)*18 | 2 | 10/17/06 |
| Samsung | M395T2953CZ4-CE61 | K4T51083QC | Samsung | | IDT | 1.5 | FDHS | (64Mx8)*18 | 2 | 10/17/06 |
| Micron | MT18HTF12872FDY-667D5E3 | MT47H64M8B6-3 | Micron | | Intel | GB C0 ¹ | FDHS | (64Mx8)*18 | 2 | 1/16/07 |
| Micron | MT18HTF12872FDY-667B5E3 | MT47H64M8CB-3 | Micron | | Intel | GB C0 ¹ | FDHS | (64Mx8)*18 | 2 | 1/16/07 |
| Micron | MT18HTF12872FDY-667D6E4 | MT47H64M8-3 | Micron | | Intel | GB D1 | FDHS | (64Mx8)*18 | 2 | 2/26/07 |
| Qimonda | HYS72T128420HFN-3S-B | HYB18T512800AF-3S-B | Qimonda | | Intel | GB D1 | FDHS | (64Mx8)*18 | 2 | 2/26/07 |
| Samsung | M395T2953EZ4-CE65 | K4T51083QE | Samsung | | Intel | GB D1 | FDHS | (64Mx8)*18 | 2 | 2/26/07 |
| Micron | MT9HTF12872FY-667E1N6 | MT47H129M8HQ-3:E | Micron | | NEC | B5+ | FDHS | (128Mx8)*9 | 1 | 3/28/07 |
| Kingston | KVR667D2D8F5/1GI | E5108AGBG-6E-E rev G | Elpida | 2025286-002.A00na | Intel | D1 | Foxconn | (64Mx8)*18 | 2 | 4/3/07 |
| Micron | MT9HTF12872FY-667E1E4 | MT47H128M8HQ-3:E | Micron | | Intel | GB D1 | FDHS | (128Mx8)*9 | 1 | 4/9/07 |
| Micron | MT9HTF12872FY-667E1D4 | MT47H128M8HQ-3:E | Micron | | IDT | C1 | FDHS | (128Mx8)*9 | 1 | 4/9/07 |
| ATP Electronics | AP28K72S8BHE6S | K4T51083QE-ZCE6 rev E | Samsung | SP240S08K1na | NEC | B5 ² | Foxconn | (64Mx8)*18 | 2 | 4/07/07 |
| Smart Modular Technologies | SG1287FBD64852IBD5 | HYB18T512800BF3S rev B | Qimonda | PG58G240NFBUB4RBS rev A | IDT | A1.5 | Foxconn | (64Mx8)*18 | 2 | 4/20/07 |
| Micron | MT18HTF12872FY-667D6E4 | MT47H128M4 | Micron | | Intel | GB D1 | FDHS | (128Mx4)*18 | 1 | 5/1/07 |
| Smart Modular Technologies | SG1287FBD64852-HB | HY5PS12821CFP-Y5 rev C | Hynix | KS-11(0646-3F) | IDT | A1.5 | Hynix | (64Mx8)*18 | 2 | 4/30/07 |
| Kingston | KVR667D2D8F5/1GI | NT5TU64M8BE-3C rev B | Nanya | 2025286-002.A00na | | D1 | Foxconn | (64Mx8)*18 | 2 | 5/22/07 |
| Crucial Technology | CT12872AF667.18FD6D4 | MT47H64M8B6-3:D | Micron | | IDT | C1 | FDHS | (64Mx8)*18 | 2 | 6/18/07 |
| Crucial Technology | CT12872AF667.18F4D6D4 | MT47H128M4B6-3:D | Micron | | IDT | C1 | FDHS | (128Mx4)*18 | 1 | 6/18/07 |
| Crucial Technology | CT12872AF667.9FE1E4 | MT47H128M8HQ-3:E | Micron | | Intel | GB D1 | FDHS | (128Mx8)*9 | 1 | 6/18/07 |
| Crucial Technology | CT12872AF667.18FD6E4 | MT47H64M8B6-3:D | Micron | | Intel | GB D1 | FDHS | (64Mx8)*18 | 2 | 6/18/07 |

¹ The GB C0 AMB revision does not support closed-loop throttling.

² This part may show voltage errors in the System Event Log (SEL) during boot. These errors will not affect system operation and can be ignored.

| Fully Buffered ECC, DDR2-667 DIMM Modules 1 GB Sizes (128Mx72) | | | | | | | | | | |
|---|--------------------------|-------------------------|--------------------|-------------------------|-------------------|---------------------|-------------------------|--------------------------|-------------|-------------|
| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
| Crucial Technology | CT12872AF667.18F4D6E4 | MT47H128M4B6-3:D | Micron | | Intel | GB D1 | FDHS | (128Mx4)*18 | 1 | 6/18/07 |
| Crucial Technology | CT12872AF667.9FE1D4 | MT47H128M8HQ-3:E | Micron | | IDT | C1 | FDHS | (128Mx8)*9 | 1 | 6/18/07 |
| Crucial Technology | CT12872AF667.9FE1N6 | MT47H128M8HQ-3:E | Micron | | IDT | C1 | FDHS | (128Mx8)*9 | 1 | 6/18/07 |
| Micron | MT18HTF12872FDY-667D6D4 | MT47H64M8B6-3:D | Micron | | IDT | C1 | FDHS | (64Mx8)*18 | 2 | 6/18/07 |
| Micron | MT18HTF12872FY-667D6D4 | MT47H128M4B6-3:D | Micron | | IDT | C1 | FDHS | (128Mx4)*18 | 1 | 6/18/07 |
| Qimonda | HYS72T128420HFE-3S-B | HYB18T512800BF | Qimonda | | NEC | B5+ | FDHS | (64Mx8)*18 | 2 | 6/18/07 |
| Qimonda | HYS72T128520HFD-3S-B | HYB18T512800BF | Qimonda | | IDT | C1 | FDHS | (64Mx8)*18 | 2 | 6/18/07 |
| Ventura Technology Group | D2-54VD80SIV-555 | K4T51083QEZCE6 rev E | Samsung | D2F28B na | IDT | A1.5 | AVC | (64Mx8)*18 | 2 | 7/18/07 |
| Samsung | M395T2953EZ4-CE66 | K4T51083QEZCE6 | Samsung | | IDT | C1 | FDHS | (64Mx8)*18 | 2 | 6/18/07 |
| Smart Modular Technologies | SG1287FBD64852-SEI | K4T510830QEZCE6 rev E | Samsung | M395T2953EZ0 na | IDT | C1 | Foxconn | (64Mx8)*18 | 2 | 9/14/07 |
| Apacer | 75.063AI.G00 | K4T51083QEZCE6 rev E | Samsung | 48.16203.095 rev 5 | Intel | D1 | AVC | (64Mx8)*18 | 2 | 9/21/07 |
| Kingston | KVR667D2D8F5/1GI | HYB18T512800BF-3S rev B | Qimonda | 2025286-002.A00 na | Intel | D1 | Foxconn | (64Mx8)*18 | 2 | 10/5/07 |
| Smart Modular Technologies | SG1287FBD64852SEC1 | K4T51083QEZCE6 rev E | Samsung | PG58G240NFBUB4RBS rev A | IDT | C1 | Foxconn | (64Mx8)*18 | 2 | 10/11/07 |
| Smart Modular Technologies | SG1287FBD64852IBDC | HYB18T512800BF3S rev B | Qimonda | PG58G240NFBUB4RBS rev A | IDT | C1 | Foxconn | 64M x 8 | | 10/22/07 |
| Hynix | HYMP512F72CP8D3-Y5 | HY5PS12821CFP-Y5 | Hynix | | IDT | C1 | FDHS | (64Mx8)*18 | 2 | 1/7/08 |
| Avant Technology | AVF7228B52E5667F1NYBP-IS | NT5TU64M8BE-25C rev B | Nanya | D2F28B rev B | IDT | C1 | Foxconn | 64M x 8 | 2 | 5/27/08 |
| Avant Technology | AVF7228B52E5667F1ELJP-IS | EDE5108AJBG-8E-E rev J | Elpida | D2F28B rev B | IDT | C1 | Foxconn | 64M x 8 | 2 | 06/02/08 |
| TRS | TRS32403X | K4T1G084QQ-HCE6 rev Q | Samsung | M395T6553EZ0-P150 rev 4 | IDT | C1 | Samsung | 128M x 8 | 1 | 10/10/08 |
| TRS | TRS32400X | HY5PS1G831CFP-Y5 rev C | Hynix | 0806-2DC | IDT | C1 | Hynix | 128M x 8 | 1 | 10/16/08 |

(+) This vendor is part of the CMTL Certification program. This means this part has/will be tested across all compatible Intel Server Boards. For further information contact CMTL @ <http://cmtlabs.com/>

Note: The use of x4 FBDIMMs will only be supported with the server system operating in "Performance" mode (default). The use of x4 FBDIMMs while the server system is configured to operate in "Acoustics" mode is not supported.

Intel® Server System SC5400RA

Fully Buffered ECC, DDR2-667 DIMM Modules

2 GB Sizes (256Mx72)

| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
|--------------------------|-----------------------------------|----------------------------|-------------|---------------------------|------------|--------------------|------------------|-------------------|------|----------|
| Qimonda | HYS72T256420 HFD-3S-A | | Qimonda | | IDT | 1.5 | HS | (128Mx4)*36 | 2 | 11/10/06 |
| Samsung | M395T5750CZ 4-CE61 | K4T51043QC | Samsung | | IDT | 1.5 | FDHS | (128Mx4)*36 | 2 | 11/14/06 |
| Qimonda | HYS72T256420 HFD-3S-A | HYB18T512400 AF-3S-A | Qimonda | | IDT | 1.5 | FDHS | (128Mx4)*36 | 2 | 1/15/07 |
| Kingston | KVR667D2D4F 5/2GI (INT/ELP) | E5104AG-6E-E | Elpida | | Intel | D1 | FDHS | (128Mx4)*36 | 2 | 2/26/07 |
| Micron | MT36HTF2567 2FY-667D1E3 | MT47H128M4B6 -3 | Micron | | Intel | GB C0 ¹ | FDHS | (128Mx4)*36 | 2 | 2/26/07 |
| Qimonda | HYS72T256420 HFD-3S-B | HYB18T512400 AF-3S-B | Qimonda | | IDT | 1.5 | FDHS | (128Mx4)*36 | 2 | 2/26/07 |
| Qimonda | HYS72T256420 HFN-3S-B | HYB18T512400 AF-3S-B | Qimonda | | Intel | GB D1 | FDHS | (128Mx4)*36 | 2 | 2/26/07 |
| Kingston | KVR667D2D4F 5/2GI | HYB18T512400 BF3S rev B | Qimonda | 2025372- 002.A00 na | Intel | D1 | Foxconn | (128Mx4)*36 | 2 | 3/14/07 |
| Kingston | KVR667D2D4F 5/2GI | NT5TU128M4AE -3C rev A | Nanya | 2025372- 002.A00 na | Intel | D1 | Foxconn | (128Mx4)*36 | 2 | 3/19/07 |
| Kingston | KVR667D2D4F 5/2GI | HYB18T512400 AF3S rev A | Qimonda | 2025372- 002.A00 na | Intel | D1 | Foxconn | (128Mx4)*36 | 2 | 04/03/07 |
| ATP Electronics | AP56K72G4BH E6S | K4T51043QE- ZCE6 rev E | Samsung | SP240G0 4K1 na | NEC | B5 ² | Foxconn | (128Mx4)*36 | 2 | 04/05/07 |
| Qimonda | HYS72T256420 HFE-3S-B | HYB18T512400 AF-3S-A | Qimonda | | NEC | B5+ | FDHS | (128Mx4)*36 | 2 | 4/9/07 |
| Samsung | M395T5750EZ4 -CE65 | K4T51043QE | Samsung | | Intel | GB D1 | FDHS | (128Mx4)*36 | 2 | 4/9/07 |
| Kingston | KVR667D2D8F 5/2GI | MT47H128M8H Q-3 rev E | Micron | 2025286- 002.A00 na | Intel | D1 | Foxconn | 128M x 8 | | 4/11/07 |
| Kingston | KVR667D2D4F 5/2GI | HY5PS12421BF P-Y5 rev B | Hynix | 0708-6A | IDT | A1.5 | AVC | (128Mx4)*36 | 2 | 4/18/07 |
| Micron | MT18HTF2567 2FY-667E1E4 | MT47H256M4 | Micron | | Intel | GB D1 | FDHS | (256Mx4)*18 | 1 | 5/1/07 |
| Micron | MT36HTF2567 2FY-667D1E4 | MT47H128M4 | Micron | | Intel | GB D1 | FDHS | (128Mx4)*36 | 2 | 5/1/07 |
| Ventura Technology Group | D2-56VF82SIV- 555 | K4T51043QC- ZCE6 rev C | Samsung | D2F24E na | IDT | A1.5 | AVC | (128Mx4)*36 | 2 | 5/16/07 |

¹ The GB C0 AMB revision does not support closed-loop throttling.

² This part may show voltage errors in the System Event Log (SEL) during boot. These errors will not affect system operation and can be ignored.

| Fully Buffered ECC, DDR2-667 DIMM Modules 2 GB Sizes (256Mx72) | | | | | | | | | | |
|---|--------------------------|-------------------------|--------------------|---------------------------|-------------------|---------------------|-------------------------|--------------------------|-------------|-------------|
| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
| Crucial Technology | CT25672AF667.18FE1D4 | MT47H256M4H Q-3:E | Micron | | IDT | C1 | FDHS | (256Mx4)*18 | 1 | 6/18/07 |
| Crucial Technology | CT25672AF667.18FE1E4 | MT47H128M8H Q-3:E | Micron | | Intel | GB D1 | FDHS | (128Mx8)*18 | 2 | 6/18/07 |
| Crucial Technology | CT25672AF667.18FE1E4 | MT47H256M4H Q-3:E | Micron | | Intel | GB D1 | FDHS | (256Mx4)*18 | 1 | 6/18/07 |
| Crucial Technology | CT25672AF667.36FD1E4 | MT47H128M4B6-3:D | Micron | | Intel | GB D1 | FDHS | (128Mx4)*36 | 2 | 6/18/07 |
| Micron | MT18HTF25672FY-667E1D4 | MT47H256M4H Q-3:E | Micron | | IDT | C1 | FDHS | (256Mx4)*18 | 1 | 6/18/07 |
| Legacy Electronics Inc. | B527M4C90EE-30R | K4T51043QC-ZCE6 rev C | Samsung | D2F24E_A rev A | IDT | A1.5 | AVC | (128Mx4)*36 | 2 | 7/9/07 |
| Legacy Electronics Inc. | M527NAE90BE-30R | MT47H128M8H Q-3 rev E | Micron | D2F28B rev B | IDT | A1.5 | AVC | (128Mx8)*18 | 2 | 7/11/07 |
| Micron | MT36HTF25672FY-667D1D4 | MT47H128M4B6-3 | Micron | | IDT | C1 | FDHS | (128Mx4)*36 | 2 | 7/16/07 |
| Smart Modular Technologies | SG2567FBD28452IBD5 | HYB18T512400 BF3S rev B | Qimonda | PG54G240 NFSUB1R ES rev C | IDT | A1.5 | Foxconn | (128Mx4)*36 | 2 | 7/23/07 |
| Samsung | M395T5750EZ4-CE66 | K4T51043QE-ZCE6 | Samsung | | IDT | C1 | FDHS | (128Mx4)*36 | 2 | 6/18/07 |
| Micron | MT18HTF25672FDY-667E1E4 | MT47H128M8H Q-3:E | Micron | | Intel | GB D1 | FDHS | (128Mx8)*18 | 2 | 9/17/07 |
| Apacer | 75.A72AI.G00 | K4T51043QE-ZCE6 rev E | Samsung | 48.1A205.011 rev 1 | Intel | D1 | AVC | (128Mx4)*36 | 2 | 9/23/07 |
| Smart Modular Technologies | SG2567FBD28452IBDC | HYB18T512400 BF3S rev B | Qimonda | PG54G240 NFSUB1R ES rev C | IDT | C1 | Foxconn | (128Mx4)*36 | 2 | 9/27/07 |
| Kingston | KVR667D2D4F5/2GI | NT5TU128M4BE-3C rev B | Nanya | 2025378-001.A00 na | Intel | D1 | Foxconn | (128Mx4)*36 | 2 | 10/07/07 |
| Kingston | KVR667D2D8F5/2GI | E1108ACBG-6E-E rev C | Elpida | 2025286-002.A00 na | Intel | D1 | Foxconn | 128M x 8 | 2 | 2/15/08 |
| Avant Technology | AVF7256B61E5667F1ELCP-IS | EDE1108ACBG-8E-E rev C | Elpida | D2F28B rev B | IDT | C1 | Foxconn | 128M x 8 | 2 | 5/30/08 |
| Avant Technology | AVF7256B61E5667F0ELCP-IS | EDE1108ACBG-8E-E rev C | Elpida | 50-1451-01A rev A | IDT | C1 | Foxconn | 128M x 8 | 2 | 6/02/08 |
| TRS | TRS32406X | K4T1G084QQ-HCE6 rev Q | Samsung | M395T2953EZ0-P110 rev 4 | IDT | C1 | Samsung | 128M x 8 | 2 | 10/09/08 |

(+) This vendor is part of the CMTL Certification program. This means this part has/will be tested across all compatible Intel Server Boards. For further information contact CMTL @ <http://cmtlabs.com/>

Note: The use of x4 FBDIMMs will only be supported with the server system operating in "Performance" mode (default). The use of x4 FBDIMMs while the server system is configured to operate in "Acoustics" mode is not supported.

Intel® Server System SC5400RA

Fully Buffered ECC, DDR2-667 DIMM Modules

4 GB Sizes (512Mx72)

| Manufacturer | Part Number | DRAM Part Number | DRAM Vendor | PCB Part Number | AMB Vendor | AMB Revision | Heat-sink Vendor | DRAM Organization | Rank | Date |
|----------------------------|----------------------------------|----------------------------|-------------|---------------------------------|------------|-----------------|------------------|-------------------|------|----------|
| Micron | MT36HTF51 272FY- 667E1D4 | MT47H256M4HQ- 3:E | Micron | | IDT | C1 | FDHS | (256Mx4)*36 | 2 | 3/28/07 |
| Micron | MT36HTF51 272FY- 667E1E4 | MT47H256M4HQ- 3:E | Micron | | Intel | GB D1 | FDHS | (256Mx4)*36 | 2 | 4/9/07 |
| Micron | MT36HTF51 272FY- 667E1N6 | MT47H256M4HQ- 3:E | Micron | | NEC | B5+ | FDHS | (256Mx4)*36 | 2 | 4/9/07 |
| Legacy Electronics Inc. | M547RAE90 EE-30R | MT47H256M4HQ- 3 rev E | Micron | D2F24E rev E | IDT | A1.5 | AVC | (256Mx4)*36 | 2 | 5/17/07 |
| ATP Electronics | AP12K72G4 BJE6M | MT47H256M4HQ- 3 rev E | Micron | SP240G04 K1 na | | B5 ² | Foxconn | (256Mx4)*36 | 2 | 5/29/07 |
| Crucial Technology | CT51272AF 667.36FE1E 4 | MT47H256M4HQ- 3:E | Micron | | Intel | GB D1 | FDHS | (256Mx4)*36 | 2 | 6/18/07 |
| Crucial Technology | CT51272AF 667.36FE1D 4 | MT47H256M4HQ- 3:E | Micron | | IDT | C1 | FDHS | (256Mx4)*36 | 2 | 6/18/07 |
| Crucial Technology | CT51272AF 667.36FE1N 6 | MT47H256M4HQ- 3:E | Micron | | IDT | C1 | FDHS | (256Mx4)*36 | 2 | 6/18/07 |
| Smart Modular Technologies | SG5127FBD 225652MEC | MT47H256M4HQ- 3 rev E | Micron | PG54G240 NFSUB2R ES rev A | IDT | C1 | Foxconn | (256Mx4)*36 | 2 | 8/06/07 |
| Smart Modular Technologies | SG5127FBD 225652-SA | K4T2G264QA- ZCE6 rev A | Samsung | M395T516 6AZ0 na | IDT | A1.5 | Samsung | (256Mx4)*36 | 2 | 8/15/07 |
| Samsung | M395T5160 CZ4-CE66 | K4T2G264QC- ZCE6 | Samsung | | IDT | C1 | FDHS | (2x256Mx4)* 18 | 2 | 6/18/07 |
| Smart Modular Technologies | SG5127FBD 225652-SC | K4T1G044QC- ZCE6 rev C | Samsung | M395T575 0EZ0 na | IDT | A1.5 | Samsung | (256Mx4)*36 | 2 | 9/6/07 |
| Smart Modular Technologies | SG5127FBD 225652SCD | K4T1G044QC- ZCE6 rev C | Samsung | M395T575 0EZ0 na | IDT | C1 | Samsung | (256Mx4)*36 | 2 | 9/12/07 |
| Apacer | 78.BHGA8.4 21 | E1104ACSE-6E-E rev C | Elpida | 48.1A205.0 11 rev 1 | IDT | C1 | AVC | (256Mx4)*36 | 2 | 10/18/07 |
| Avant Technology | AVF7251B6 2E5667F4E LCP-IS | EDE1104ACSE- 8E-E rev C | Elpida | BA2FRCU 3.10 rev 3.10 | IDT | C1 | Foxconn | 256M x 4 | 2 | 5/31/08 |
| TRS | TRS32409X | K4T1G044QQ- HCE6 rev Q | Samsung | M395T575 0EZ0-P081 rev 4 | IDT | C1 | Samsung | 256M x 4 | 2 | 10/12/08 |

² This part may show voltage errors in the System Event Log (SEL) during boot. These errors will not affect system operation and can be ignored.

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Note: The use of x4 FBDIMMs will only be supported with the server system operating in “Performance” mode (default). The use of x4 FBDIMMs while the server system is configured to operate in “Acoustics” mode is not supported.

Sales Information

| Vendor Name | Web URL | Vendor Direct Sales Info |
|--------------------------------|---|--|
| ATP Electronics | http://www.atpinc.com/ | Tel (1) 408-732-5000, ext 5858 Fax 408-732-5893 sales@atpusa.com |
| ATP Electronics -- Taiwan Inc. | http://www.atpinc.com/ | Tel 011-886-2-2659-6368 Fax 886-2-2659-4982 |
| Avant Technology | http://www.avanttechnology.com | Brad Scoggins Phone: (512)491-7411 Fax: (512)491-7412 brads@avanttechnology.com |
| Aved Memory Products | http://www.avedmemory.com/ | |
| Buffalo Technology | http://www.buffalotech.com/ | (800) 967-0959 memory@buffalotech.com |
| Centon Electronics | http://www.centon.com | Tel: 949-855-9111 Fax: 949-855-6035 |
| Corsair | http://www.corsairmicro.com/ | Tel: 510-657-8747 Fax: 510-657-8748 |
| Dane-Elec | http://www.dane-memory.com/ | Michal Hassan @ (949)450-2941 or email @ Michal@Dane-memory.com |
| Dataram | http://www.dataram.com/ | Paul Henke, 800-328-2726 x2239 in USA 609-799-0071 phenke@dataram.com |
| GoldenRAM | http://www.goldenram.com | Jason M. Barrette @ 800-222-861 x7546 jasonb@goldenram.com or Michael E. Meyer @800-222-8861 x7512 michaelm@goldenram.com |
| Hitachi | http://semiconductor.hitachi.com/pointer/ | |
| Hyundai/Hynix Semiconductor | http://www.heacom/ | |
| Qimonda (Infineon) | http://www.Qimonda(Infineon).com/business/distribut/index.htm | |
| ITAUCOM | http://www.itaucocom.br | |
| JITCO CO LTD | http://www.jitco.net/ | Seong Jeon Tel: 82-32-817-9740 s.jeon@jitco.net |
| Kingston | http://www.kingston.com | US.- Call (877) 435-8726 Asia – Call 886-3-564-1539 Europe – Call +44-1932-755205 |
| Legacy Electronics Inc. | http://www.legacyelectronics.com | U.S. Contact: Gary Ridenour, 949-498-9600, Ext 350 European Contact: 49 89 370 664 11 |
| Legend | http://www.legend.com.au | |
| Micron | http://silicon.micron.com/mktg/ http://silicon.micron.com/mktg/mbqual/qual_data.cfm | |
| MSC Vertriebs GmbH | http://www.msc-ge.com | William Perrigo 49-7249-910-417 Fax: 49-7249-910-229 wpe@msc-ge.com |
| Nanya Technology | http://www.ntc.com.tw | Winson Shao 886-3-328-1688, Ext 6018 winsonshao@ntc.com.tw |

| Vendor Name | Web URL | Vendor Direct Sales Info |
|----------------------------|--|---|
| Netlist, Inc | http://www.netlistinc.com | Christopher Lopes 949.435.0025 tel 949.435.0031 fax sales@netlistinc.com |
| Peripheral Enhancements | http://www.peripheral.com/ | |
| Samsung | http://www.korea.samsungsemi.com/locate/buy/list_na.html | For US customers go to: http://www.mymemorystore.com/ |
| Silicon Tech | http://www.silicontech.com/contact/salescontacts.shtml | |
| Simple Tech | http://www.simpletech.com | Ron Darwish @ (949) 260-8230 or email @ Rdarwish@Simpletech.com |
| SMART Modular Technologies | www.smartm.com/channel/hpc/ | Gene Patino (949) 439-6167 Gene.Patino@Smartm.com |
| Super Talent Electronics | http://www.supertalentmemory.com | David Crume (408) 957-8181 support@supertalentmemory.com |
| Swissbit | http://www.swissbit.com | Tony Cerreta Tel: 914-935-1400 x240 Fax: 914-935-9865 tony.cerreta@swissbitna.com |
| TechnoLinc Corporation | http://www.technolinc.com | David Curtis 510-445-7400 davidc@technolinc.com |
| TRS* Tele-Radio-Space GmbH | http://www.certified-memory.com http://www.certified-memory.de | Vender Direct Sales Info: Andreas Gruendl Tel: +49.89.945532-34 Fax: +49.89.945532-41 Andreas.gruendl@trs-eu.com |
| Unigen | http://www.unigen.com | |
| Ventura Technology Inc | http://www.venturatech.com | Sam Lewis 760 724-8700 ext. 103 |
| Viking InterWorks | http://www.vikinginterworks.com | Adrian Proctor Tel: 949-643-7255 adrian.proctor@sanmina-sci.com |
| Virtium Technology Inc | http://www.virtium.com | Tod Skelton @ (949) 460-0020 ext. 146 or email @ tod.skelton@virtium.com |
| Wintec Industries | http://www.wintecindustries.com | Tel 510-360-6300 Fax 510-770-9338 |

CMTL* (Computer Memory Test Labs)

CMTL is a privately owned and operated memory testing organization responsible for testing a broad range of memory products. Memory devices tested by CMTL must undergo a rigorous battery of tests to ensure that the product will perform the intended server functions. Memory capability is a major factor your customers consider. CMTL has the ability to test and certify memory on Intel-based server platforms. The list of memory modules, which have undergone testing through the CMTL facility, should be referenced when considering modules for integration into this Intel server product. Stringent standards with regard to manufacturing procedures and quality must be met to pass the exacting tests required for qualification through the independent testing facility. Testing is performed by CMTL with Intel server products and test procedures defined by Intel's Memory Qualification Lab. Intel routinely audits the CMTL facility to ensure all procedures, process handling, and testing methodologies are met.

IMPORTANT NOTE

DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or vice-versa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each Rank on the memory module. Mixing of dissimilar memory manufacturer devices or dissimilar memory device speeds is not recommended. This document contains information which is the proprietary property of Intel Corporation. Nothing in this document constitutes a guaranty, warranty, or license, express or implied. Intel has tested the following DIMMs for minimum electrical and functional compatibility with the Intel® Server System. This listing is not intended to be all inclusive; it only represents the DIMMs Intel or CMTL has tested. Users of this list are reminded to check with the DIMM manufacturer or Distributor to ensure that a particular DIMM model is adequate for the intended purpose of the Intel® Server System. Intel provides no indemnities for and expressly disclaims all liabilities for any and all such guaranties, representations, and warranties (oral or written) whether express or implied, related to DIMMs in an Intel® Server System product, including without limitation to: fitness for a particular purpose; merchantability; noninfringement of intellectual property or other rights of any third party or of Intel. The reader is advised that third parties may have intellectual property rights which may be relevant to this document and the technologies discussed herein, and is advised to seek the advice of competent legal counsel, without obligation of Intel. Intel retains the right to make changes to this document at any time, without notice. Intel makes no warranty or representation with respect to the use of this document or reliance by the reader upon its contents, and assumes no responsibility for any errors which may appear in the document nor does it make a commitment to update the information contained herein.

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